



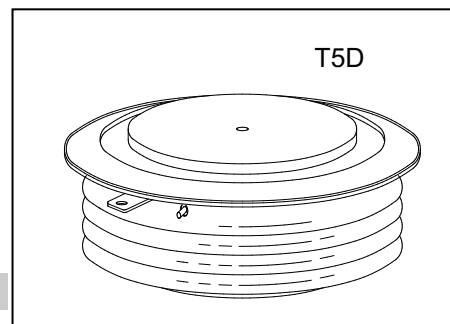
KP350-POWER THYRISTOR

6000-6600 V_{RSM}

FREE FLOATING TYPE THYRISTOR FOR PHASE CONTROL APPLICATIONS

Features:

- . Free-floating silicon technology
- . Low on-state and switching losses
- . Optimum power handling capability
- . Blocking capability up to 6600 volts
- . Distributed amplifying gate



ELECTRICAL CHARACTERISTICS AND RATINGS

Blocking - Off State

Device Type	V _{RRM} (1)	V _{DRM} (1)	V _{RSM} (1)
KP350/60	5100	5100	6000
KP350/62	5300	5300	6200
KP350/65	5600	5600	6500
KP350/66	5700	5700	6600

V_{RRM} = Repetitive peak reverse voltage

V_{DRM} = Repetitive peak off state voltage

V_{RSM} = Non repetitive peak reverse voltage (2)

Notes:

- (1) All voltage ratings are specified for an applied 50Hz sinusoidal waveform over the temperature range -40 °C to +125 °C.
- (2) 10 msec. max. pulse width
- (3) Maximum value for T_j = 125 °C.
- (4) Minimum value for linear and exponential waveshape to 67% rated V_{DRM}. Gate open. T_j = 125 °C.
- (5) The value of di/dt is established in accordance with EIA/NIMA Standard JB/T 8950.2-2013

Repetitive peak reverse leakage and off state leakage	I _{RRM} /I _{DRM}	2 mA 70 mA (3)
Critical rate of voltage rise	dv/dt (4)	2000 V/μs

Conducting - On State

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average value of on-state current	I _{T(AV)}		350		A	Sinewave, 180° conduction, T _c =70°C
RMS value of on-state current	I _{TRMS}		550		A	Nominal value
Peak one cycle surge (non repetitive) current	I _{TSM}		5600		A	10.0 msec (50Hz), sinusoidal wave-shape, 180° conduction, T _j = 125 °C
I square t	I ² t		1.57x10 ⁵		A ² s	10 msec
Latching current	I _L		1000		mA	V _D = 12 V; R _L = 12 ohms
Holding current	I _H		200		mA	V _D = 12 V; I = 2.5 A
Peak on-state voltage	V _{TM}		3.4		V	I _{TM} =1000A; T _j =25°C
Threshold voltage, low-level	V _{TO}		1.1		V	T _j =125°C
Slope resistance, low-level	r _T		2.3		mΩ	600A to 1800A
Critical rate of rise of on-state current(5)	di/dt		150		A/μs	T _j =125°C; V _D = 0.67 V _{DRM} ; f=50Hz; I _{TM} =1000A

Gating

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Peak gate power dissipation	P_{GM}		20		W	
Average gate power dissipation	$P_{G(AV)}$		4		W	
Gate-trigger current	I_{GT}		200		mA	$V_D = 12\text{ V}; R_L = 3\text{ ohms}; T_j = +25\text{ }^{\circ}\text{C}$
Gate- trigger voltage	V_{GT}	0.7	2.6		V	$V_D = 12\text{ V}; R_L = 3\text{ ohms}; T_j = +25\text{ }^{\circ}\text{C}$
Peak negative voltage	V_{GRM}		10		V	

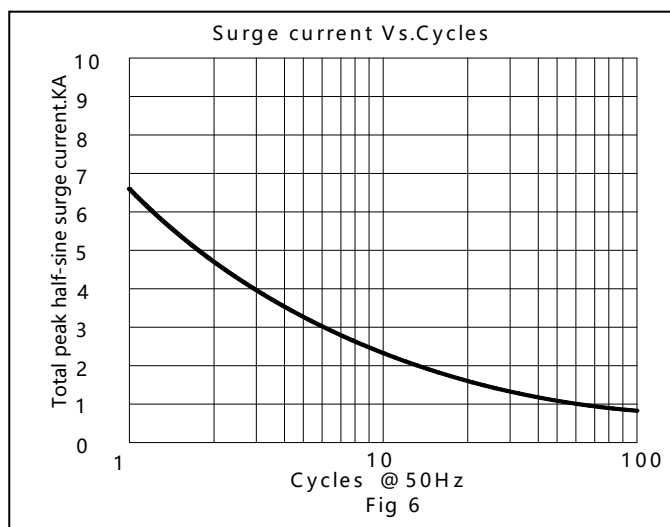
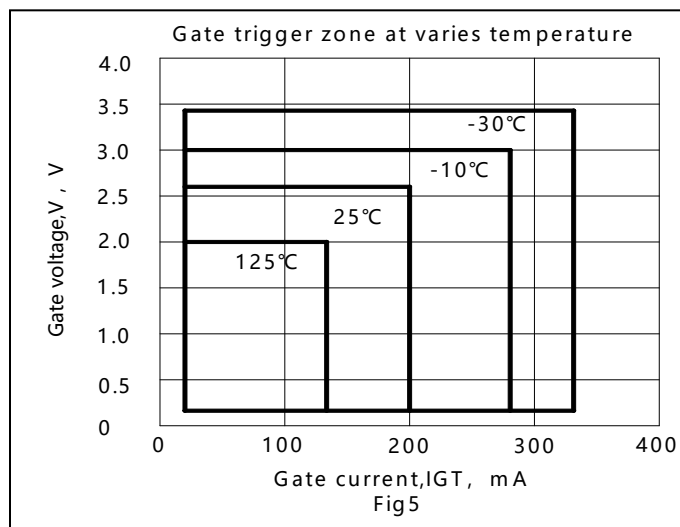
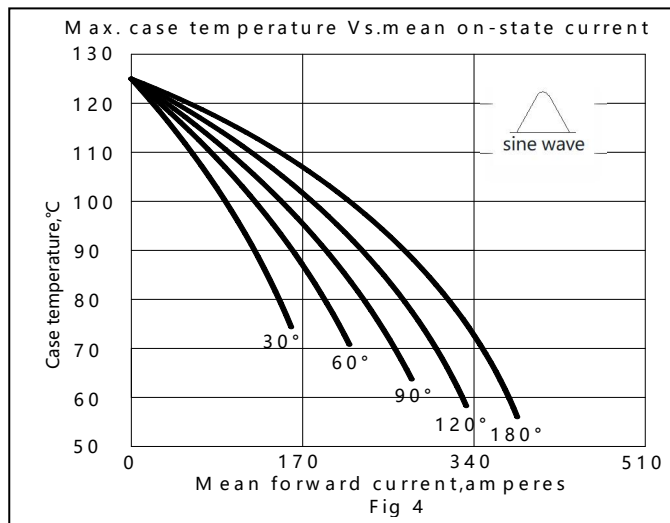
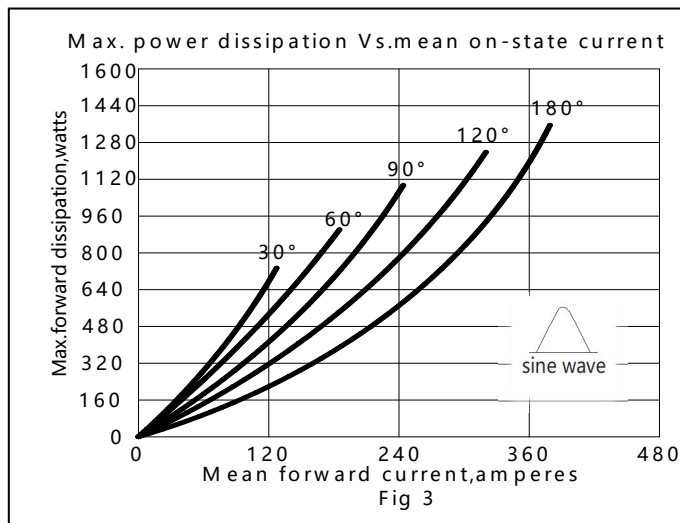
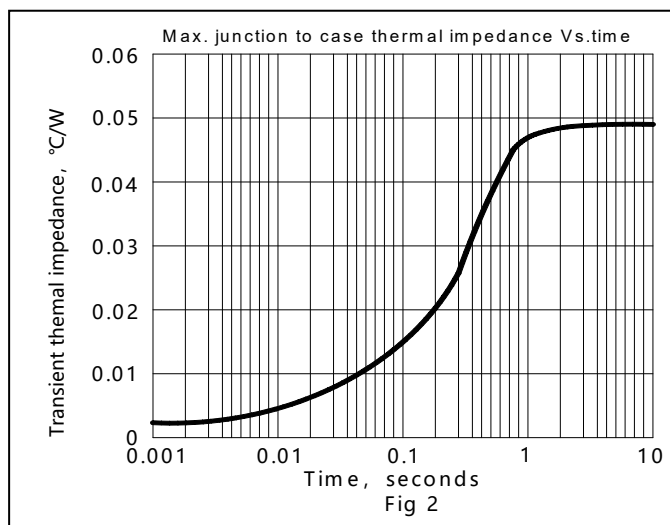
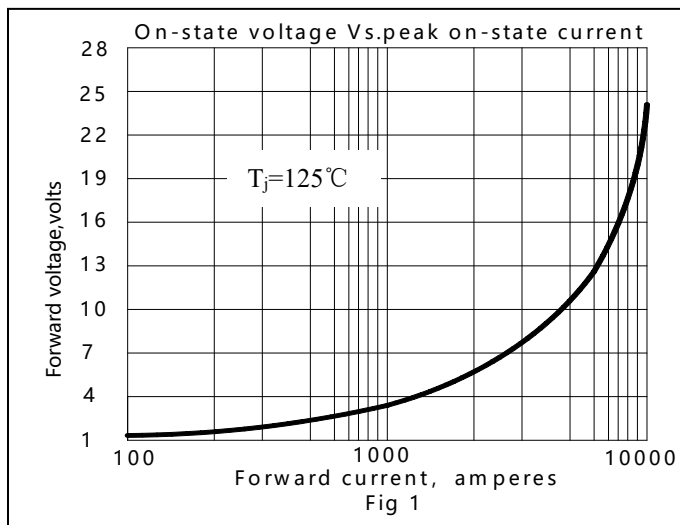
Dynamic

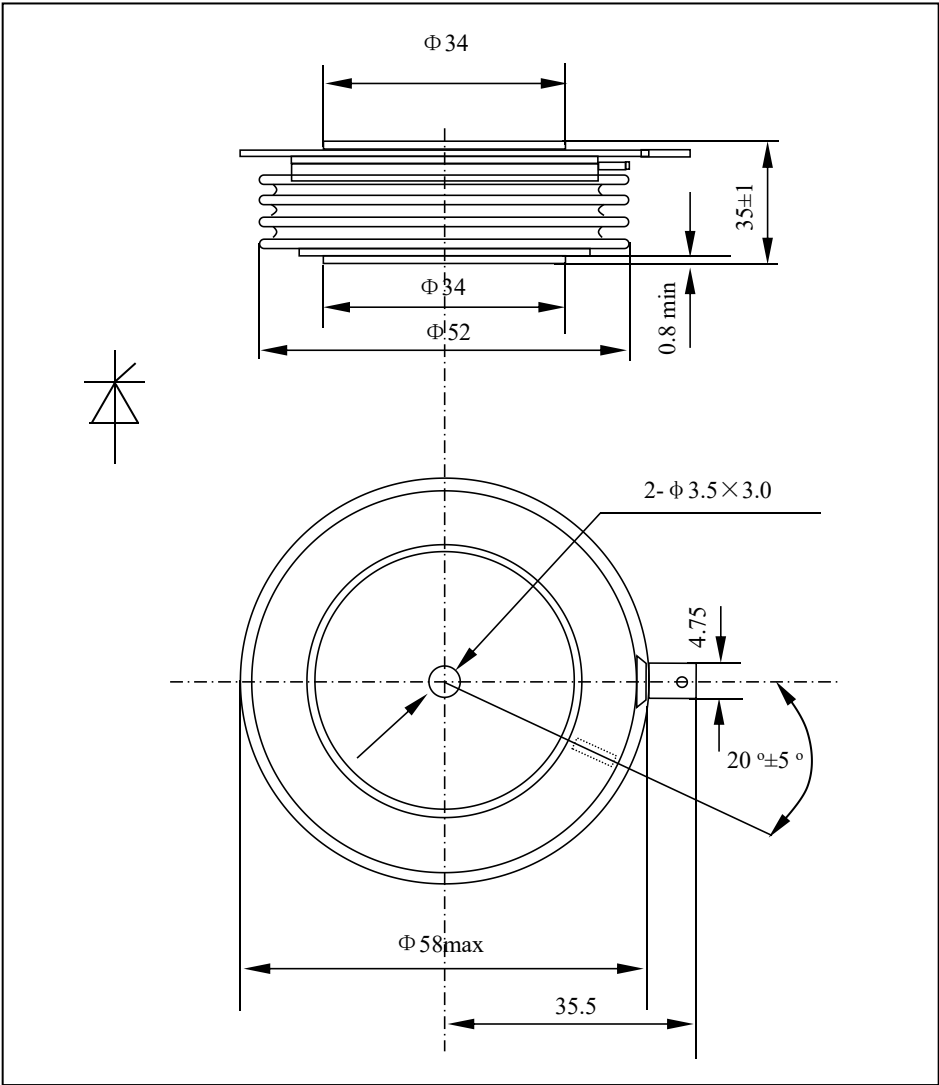
Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Delay time	t_d			3.0	μs	$I_{TM}=100\text{A}; V_D=67\%V_{DRM}$ Gate pulse: $V_G=30\text{V}; R_G=10\text{ohms};$ $t_r=0.1\mu\text{s}; t_p=20\mu\text{s}$
Turn-off time (with $V_R = -5\text{ V}$)	t_q			700	μs	$I_{TM} = 1000\text{A}; di/dt = -10\text{A}/\mu\text{s};$ $V_R = 100\text{V}; dv/dt = 30\text{V}/\mu\text{s};$ $V_D = 67\%V_{DRM}; T_j = 125^{\circ}\text{C}$
Reverse recovery charge	Q_{rr}		1900		μC	$I_{TM}=1000\text{A}; di/dt=-10\text{A}/\mu\text{s};$ $V_R=100\text{V}; T_j=125^{\circ}\text{C}$

THERMAL AND MECHANICAL CHARACTERISTICS AND RATINGS

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T_j	-40	+125		$^{\circ}\text{C}$	
Storage temperature	T_{stg}	-40	+140		$^{\circ}\text{C}$	
Thermal resistance - junction to case	$R_{\Theta(j-c)}$		0.045		$^{\circ}\text{C}/\text{W}$	Double sided cooled
Thermal resistance - case to heatsink	$R_{\Theta(c-s)}$		0.008		$^{\circ}\text{C}/\text{W}$	Double sided cooled
Mounting force	F	14	16	15	kN	
Weight	m			0.4	kg	

* Mounting surfaces smooth, flat and greased





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